

# Automotive LPDDR5X SDRAM

MT62F1G32D2, MT62F2G32D4, MT62F4G32D8

## Features

- **Architecture**
  - 19.2 GB/s maximum bandwidth per channel
  - Frequency range: 1200–5 MHz (data rate range per pin: 9600–40 Mb/s with WCK:CK = 4:1)
  - Selectable CKR (WCK:CK = 2:1 or 4:1)
- **LPDDR5X/LPDDR5 data interface**
  - Single x16 channel/die
  - Double-data-rate command/address entry
  - Differential command clocks (CK<sub>t</sub>/CK<sub>c</sub>) for high-speed operation
  - Differential data clocks (WCK<sub>t</sub>/WCK<sub>c</sub>)
  - Optional differential read strobe (RDQS<sub>t</sub>/RDQS<sub>c</sub>)
  - 16n-bit or 32n-bit prefetch architecture
  - Bank Architecture: Bank Group (BG) mode, and 16-bank (16B) mode supported
  - Command-selectable burst lengths (BL = 16 or 32) in bank group or 16-bank modes
  - Background ZQ cal/Cmd-based ZQ calibration
  - Optional link protection (link ECC)
  - Partial-array self refresh (PASR) and partial-array auto refresh (PARC) with segment mask
- **Ultra-low-voltage core and I/O power supplies**
  - V<sub>DD1</sub> = 1.70–1.95V; 1.80V TYP
  - V<sub>DD2H</sub> = 1.01–1.12V; 1.05V TYP
  - V<sub>DD2L</sub> = V<sub>DD2H</sub> or 0.87–0.97V; 0.90V TYP
  - V<sub>DDQ</sub> = 0.50V or 0.45V<sup>1</sup> TYP; 0.30V TYP (ODT off only)
- **I/O characteristics**
  - Interface-LVSTL 0.5/0.3
  - I/O type: Low-swing single-ended, V<sub>SS</sub> terminated
  - V<sub>OH</sub>-compensated output drive
  - Programmable V<sub>SS</sub> on-die termination (ODT)
  - Non target ODT support
  - DVFSQ support
  - Per byte and per pin DFE support
- **Low power features**
  - Enhanced DVFSC: Enhanced dynamic voltage frequency scaling core
  - Single-ended (CK, WCK, RDQS)
  - Data copy
  - Write X

## Options

- **Operating Voltage**
  - V<sub>DD1</sub>/V<sub>DD2H</sub>/V<sub>DD2L</sub>/V<sub>DDQ</sub>/V<sub>DDQ</sub> (ODT off only): 1.80V/1.05V/V<sub>DD2H</sub> or 0.90V/0.50V or 0.45V<sup>1</sup>/0.30V
- **Array Configuration**
  - 1Gb x 32 (1Gbx16 x 1die x 2Ch x 1R)
  - 2Gb x 32 (1Gbx16 x 1die x 2Ch x 2R)
  - 4Gb x 32 (2Gbx8 x 2 die x 2Ch x 2R)
- **Device configuration**
  - 2 die in package (1Gb16 x 2 die)
  - 4 die in package (1Gb16 x 4 die)
  - 8 die in package (2Gb8 x 8 die)
- **FBGA RoHS-compliant “green” package**
  - 315-ball TFBGA  
12.4mm x 15.0mm (TYP),  
seated height 1.1mm (MAX)
  - 315-ball LFBGA  
12.4mm x 15.0mm (TYP),  
seated height 1.3mm (MAX)
- **Speed grade, cycle time (t<sub>WCK</sub>)**
  - 9600 Mb/s
- **Functional safety, DLEP & RAS**
  - ISO 26262 ASIL D and IEC 61508 SIL 3 compliant
  - ASIL D/SIL 3 systematic fault coverage
  - Suitable for meeting random HW metrics up to ASIL D/SIL 3
  - Micron safety documentation
  - Micron safety features enabled
  - Direct Link ECC Protocol (DLEP)
  - Improved RAS
- **Automotive**
- **Operating temperature:**
- **Revision**

## Marking

F  
F  
1G32  
2G32  
4G32  
D2  
D4  
D8  
DS  
DV  
-020  
F<sup>2</sup>  
A  
IT  
AT  
UT<sup>3</sup>  
:D

Notes: 1. V<sub>DDQ</sub> = 0.45V (TYP) support on all packages up to 7500 Mb/s.  
2. For functional safety documentation to aid in ISO 26262 functional safety system design, contact Micron sales representative.

3. Based on automotive usage model. Contact Micron sales representative with questions.

## Part Number Ordering Information (Die Rev D)

Figure 1: Part Number Chart

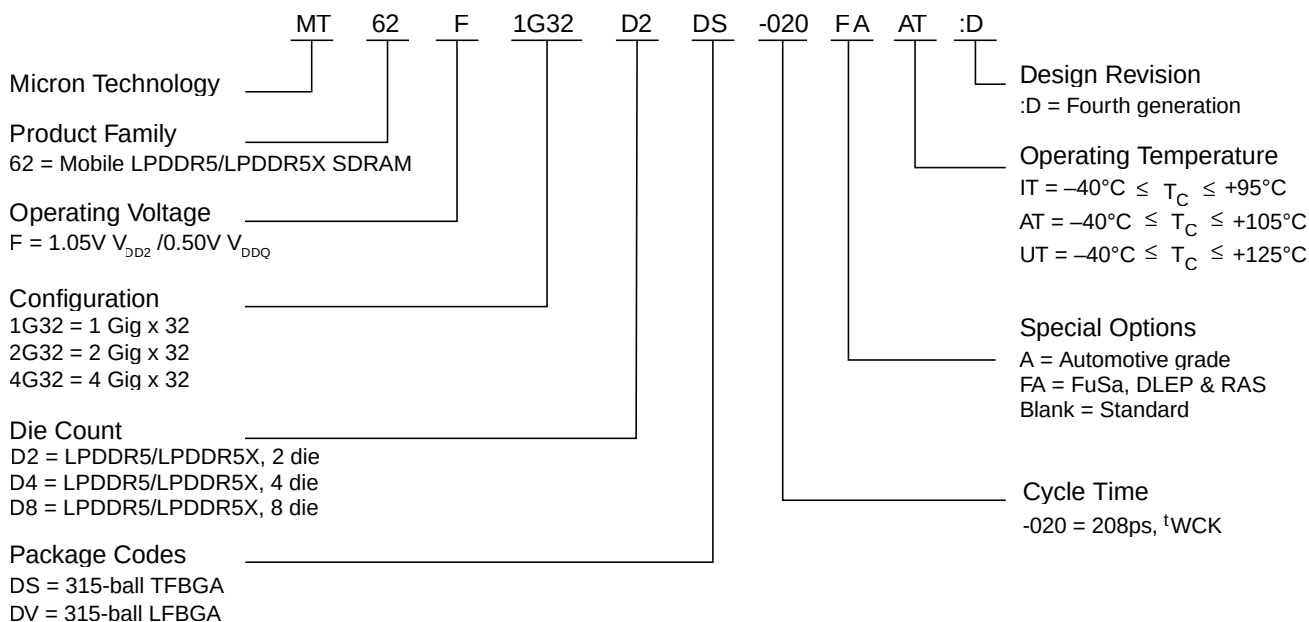


Table 1: Part Number List

| Part Number             | Total Density | Data Rate per Pin |
|-------------------------|---------------|-------------------|
| MT62F1G32D2DS-020AIT:D  | 4GB (32Gb)    | 9600 Mb/s         |
| MT62F1G32D2DS-020AAT:D  |               |                   |
| MT62F1G32D2DS-020AUT:D  |               |                   |
| MT62F1G32D2DS-020FAIT:D |               |                   |
| MT62F1G32D2DS-020FAAT:D |               |                   |
| MT62F1G32D2DS-020FAUT:D |               |                   |
| MT62F2G32D4DS-020AIT:D  | 8GB (64Gb)    |                   |
| MT62F2G32D4DS-020AAT:D  |               |                   |
| MT62F2G32D4DS-020AUT:D  |               |                   |
| MT62F2G32D4DS-020FAIT:D |               |                   |
| MT62F2G32D4DS-020FAAT:D |               |                   |
| MT62F2G32D4DS-020FAUT:D |               |                   |
| MT62F4G32D8DV-020AIT:D  | 16GB (128Gb)  |                   |
| MT62F4G32D8DV-020AAT:D  |               |                   |
| MT62F4G32D8DV-020AUT:D  |               |                   |
| MT62F4G32D8DV-020FAIT:D |               |                   |
| MT62F4G32D8DV-020FAAT:D |               |                   |
| MT62F4G32D8DV-020FAUT:D |               |                   |

## FBGA Part Marking Decoder

Due to space limitations, FBGA-packaged components have an abbreviated part marking that is different from the part number. Micron's FBGA part marking decoder is available at [www.micron.com/decoder](http://www.micron.com/decoder).

## LPDDR5/LPDDR5X Data Sheet List

For general LPDDR5/LPDDR5X specifications, please refer to the data sheets below.

- General LPDDR5/LPDDR5X Specifications 1: Mode Registers
- General LPDDR5/LPDDR5X Specifications 2: AC/DC and Interface Specifications
- General LPDDR5/LPDDR5X Specifications 3: Features and Functionalities

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## Important Notes and Warnings

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**System Design and Implementation.** This product has been developed for multiple applications based on assumed use cases and requirements (including assumed functional safety requirements and constraints). It is the customer's sole responsibility to evaluate and confirm the validity and suitability of Micron's product datasheet, assumed use cases and requirements, and evaluation results by verifying Micron's assumptions against actual use cases and requirements in the intended end system and application. The customer must ensure compliance with all applicable requirements and standards (including industry, product, security, privacy, safety, etc.) to its system and applications. The customer must protect against death, personal injury, and severe property and environmental damage by ensuring that adequate design and redundancy (as needed), manufacturing and operating safeguards are included into customer's applications to ensure that failure of the Micron component will not result in such harms.

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## General Notes

Throughout the data sheet, figures and text refer to DQs as DQ. DQ should be interpreted as any or all DQs collectively, unless specifically stated otherwise.

RDQS, CK, and WCK should be interpreted as RDQS\_t, RDQS\_c, CK\_t, CK\_c, and WCK\_t, WCK\_c respectively unless specifically stated otherwise. CA includes all CA pins used for a given density.

In timing diagrams, CMD is used as an indicator only. Actual signals occur on CA[6:0].

$V_{REF}$  indicates  $V_{REF(CA)}$ ,  $V_{REF(CS)}$ , and  $V_{REF(DQ)}$ .

Complete functionality is described throughout the entire document. Any page or diagram may have been simplified to convey a topic and may not be inclusive of all requirements.

Any content defined in this device ID specific data sheet document takes precedence over similar content defined in the general core LPDDR5/LPDDR5X SDRAM data sheet document(s).

Any functionality not specifically stated herein is considered undefined, illegal, is not supported, and will result in unknown operation.



## Automotive Product Notes

The automotive LPDDR5/LPDDR5X DRAM Product family ("A" parts - see Part Number Ordering Information) are not allowed to be used in functional safety (ASIL/SIL rated) applications. Should customer or distributor purchase, use, or sell any Micron "A" component for any functional safety (ASIL/SIL rated) application, customer and distributor shall indemnify and hold harmless Micron and its subsidiaries, subcontractors, and affiliates and the directors, officers, and employees of each against all claims, costs, damages, and expenses and reasonable attorneys' fees arising out of, directly or indirectly, any claim of product liability, personal injury, or death arising in any way out of such functional safety (ASIL/SIL rated) application, whether or not Micron or its subsidiaries, subcontractors, or affiliates were negligent in the design, manufacture, or warning of the Micron product.

## Functional Safety, DLEP & RAS Product Notes

This functional safety, DLEP and improved RAS LPDDR5/LPDDR5X DRAM product family ("F" parts - see Part Numbering Ordering Information). This product has been developed according to ISO 26262:2018 and IEC 61508:2010 requirements for use in functional safety systems targeting up to ASIL D / SIL 3 compliance.

The functional safety, DLEP and improved RAS LPDDR5/LPDDR5X DRAM product family contains several new features that operate within the JEDEC LPDDR5/LPDDR5X protocols (commands, timings, and so forth) and are made available to the integrator on "F" parts. The specification addendum governing these functional safety, DLEP and improved RAS features is available under NDA. This LPDDR5/LPDDR5X DRAM may operate as a standard JEDEC LPDDR5/LPDDR5X DRAM only, or as a standard JEDEC LPDDR5/LPDDR5X DRAM specifically designed with functional safety, DLEP and improved RAS features (only available on "F" parts).

Additional support is available to customers who need to integrate Micron's products in their functional safety-related applications. This support may include Safety Analysis Report, reporting FMEDA results and metrics, Safety Manual and Pin FMEA Report, providing guidelines and instructions for using Micron products in safety-related applications.

Contact a Micron sales representative to initiate the process required to obtain the functional safety documentation.

## Device Configuration (x32)

**Table 2: Die Organization in the Package (x32)**

| Die Organization           | 1G32 (32 Gb/package) | 2G32 (64 Gb/package) | 4G32 (128 Gb/package) |
|----------------------------|----------------------|----------------------|-----------------------|
| Channel A                  | x16 mode × 1 die     | –                    | –                     |
| Channel B                  | x16 mode × 1 die     | –                    | –                     |
| Channel A, rank 0          | –                    | x16 mode × 1 die     | –                     |
| Channel B, rank 0          | –                    | x16 mode × 1 die     | –                     |
| Channel A, rank 1          | –                    | x16 mode × 1 die     | –                     |
| Channel B, rank 1          | –                    | x16 mode × 1 die     | –                     |
| Channel A, rank 0 DQ[7:0]  | –                    | –                    | x8 mode × 1 die       |
| Channel A, rank 1 DQ[7:0]  | –                    | –                    | x8 mode × 1 die       |
| Channel B, rank 0 DQ[7:0]  | –                    | –                    | x8 mode × 1 die       |
| Channel B, rank 1 DQ[7:0]  | –                    | –                    | x8 mode × 1 die       |
| Channel A, rank 0 DQ[15:8] | –                    | –                    | x8 mode × 1 die       |
| Channel A, rank 1 DQ[15:8] | –                    | –                    | x8 mode × 1 die       |
| Channel B, rank 0 DQ[15:8] | –                    | –                    | x8 mode × 1 die       |
| Channel B, rank 1 DQ[15:8] | –                    | –                    | x8 mode × 1 die       |

Note: 1. Refer to the Package Block Diagram section in this data sheet.

**Table 3: Die Addressing**

| Description                     | 1G32 (32 Gb/package), 2G32 (64 Gb/package) |                            | 4G32 (128 Gb/package)           |                            |
|---------------------------------|--------------------------------------------|----------------------------|---------------------------------|----------------------------|
| Density per die                 | 16Gb                                       |                            | 16Gb                            |                            |
| Bits                            | 17,179,869,184                             |                            | 17,179,869,184                  |                            |
| Bank mode                       | BG mode                                    | 16B mode                   | BG mode                         | 16B mode                   |
| Configuration                   | 64Mb × 16 DQ ×<br>4 Banks × 4BG            | 64Mb × 16 DQ ×<br>16 Banks | 128Mb × 8 DQ ×<br>4 Banks × 4BG | 128Mb × 8 DQ ×<br>16 Banks |
| Number of banks                 | 4                                          | 16                         | 4                               | 16                         |
| Number of bank groups           | 4                                          | 1                          | 4                               | 1                          |
| Array prefetch bits             | 256                                        | 256                        | 128                             | 128                        |
| Rows per bank                   | 65,536                                     |                            | 131,072                         |                            |
| Columns                         | 64                                         |                            | 64                              |                            |
| Page size (bytes)               | 2048                                       | 2048                       | 1024                            | 1024                       |
| Native burst length             | 16                                         | 16                         | 16                              | 16                         |
| Number of I/Os                  | 16                                         |                            | 8                               |                            |
| Bank address                    | BA[1:0]                                    | BA[3:0]                    | BA[1:0]                         | BA[3:0]                    |
| Bank group address              | BG[1:0]                                    | –                          | BG[1:0]                         | –                          |
| Row address                     | R[15:0]                                    |                            | R[16:0]                         |                            |
| Column address                  | C[5:0]                                     |                            | C[5:0]                          |                            |
| Burst address                   | B[3:0]                                     | B[3:0]                     | B[3:0]                          | B[3:0]                     |
| Burst starting address boundary | 128-bit                                    |                            | 128-bit                         |                            |

Note: 1. Refer to the SDRAM Addressing section in General LPDDR5/LPDDR5X Specifications 3.

## Refresh Requirement Parameters

**Table 4: Refresh Requirement Parameters**

| Parameter                                                  | Symbol               | 16Gb Die                |                        | Unit |
|------------------------------------------------------------|----------------------|-------------------------|------------------------|------|
|                                                            |                      | BG and 16B Mode         |                        |      |
|                                                            |                      | Enhanced DVFSC Disabled | Enhanced DVFSC Enabled |      |
| REFRESH cycle time (all banks)                             | <sup>t</sup> RFCab   | 280                     | 300                    | ns   |
| REFRESH cycle time (per bank)                              | <sup>t</sup> RFCpb   | 140                     | 150                    | ns   |
| Per bank refresh to per bank refresh time (different bank) | <sup>t</sup> PBR2PBR | 90                      | 100                    | ns   |
| Per bank refresh to ACTIVATE command time (different bank) | <sup>t</sup> PBR2ACT | 7.5                     | 7.5                    | ns   |

Note: 1. This table only describes refresh parameters that are density dependent. Refer to Refresh Requirement section in General LPDDR5/LPDDR5X Specifications 3 for all refresh parameters.

## CS Rx Relaxed Specification

**Table 5: CS Rx Specifications**

| Item                                                | Symbol              | Min/<br>Max | CK Frequency (MHz)      |     |     |     |     |     |     |     |     |     |     |     | Unit                 | Note |       |
|-----------------------------------------------------|---------------------|-------------|-------------------------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|----------------------|------|-------|
|                                                     |                     |             | 67 <sup>6</sup>         | 133 | 200 | 266 | 344 | 400 | 467 | 533 | 600 | 688 | 750 | 800 |                      |      | 937.5 |
| Rx mask                                             |                     |             |                         |     |     |     |     |     |     |     |     |     |     |     |                      |      |       |
| CS Rx mask height                                   | vCSIVW              | Max         | 155                     |     |     |     |     |     |     |     |     |     |     |     | mV                   | 2, 7 |       |
| CS Rx mask width at V <sub>REF</sub> CS             | <sup>t</sup> CSIVW1 | Max         | 0.3                     |     |     |     |     |     |     |     |     |     |     |     | <sup>t</sup> CK(avg) | 1    |       |
| CS Rx mask width at vCSIVW                          | <sup>t</sup> CSIVW2 | Max         | 0.22                    |     |     |     |     |     |     |     |     |     |     |     | <sup>t</sup> CK(avg) | 1    |       |
| Rx single pulse                                     |                     |             |                         |     |     |     |     |     |     |     |     |     |     |     |                      |      |       |
| CS Rx pulse amplitude                               | vCSIHL_AC           | Min         | 240                     |     |     |     |     |     |     |     |     |     |     |     | mV                   | 3    |       |
| CS reference voltage                                | vREFCS              |             | V <sub>DD2H</sub> /3    |     |     |     |     |     |     |     |     |     |     |     | mV                   |      |       |
| CS Rx pulse width                                   | <sup>t</sup> CSIPW  | Min         | 0.6                     |     |     |     |     |     |     |     |     |     |     |     | <sup>t</sup> CK(avg) |      |       |
| Power down                                          |                     |             |                         |     |     |     |     |     |     |     |     |     |     |     |                      |      |       |
| CS V <sub>IL</sub> during power down/<br>deep sleep | V <sub>ILPD</sub>   | Max         | 130                     |     |     |     |     |     |     |     |     |     |     |     | mV                   | 4    |       |
| CS V <sub>IH</sub> during power down/<br>deep sleep | V <sub>IHPD</sub>   | Min         | 550                     |     |     |     |     |     |     |     |     |     |     |     | mV                   | 5    |       |
|                                                     |                     | Max         | V <sub>DD2H</sub> + 200 |     |     |     |     |     |     |     |     |     |     |     |                      |      |       |

- Notes: 1. CS Rx mask voltage and timing parameters at the pin include temperature drift and voltage AC noise impact based on Z(f) specification at a fixed temperature on the package. The voltage supply noise must comply to the component min/max DC operating conditions.
2. CS single-pulse signal amplitude into the receiver must meet or exceed  $v_{CSIHL\_AC}$  at any point over the total UI; No timing requirement above a certain level.  $v_{CSIHL\_AC}$  is the peak-to-peak voltage centered around  $V_{REF}$  CS such that  $v_{CSIHL\_AC}/2$  min has to be met both above and below  $V_{REF}$  CS.
3.  $v_{CSIHL\_AC}$  does not have to be met when no transitions are occurring.
4. The input voltage presented to the CS Rx pin during power down should be 0V nominally to minimize leakage current.
5.  $V_{IHPD}$  is only applied for POWER DOWN and DEEP SLEEP EXIT operations.

6. The Rx voltage and absolute timing requirements apply for all CS operating frequencies at or below 67 for all speed bins. For example,  $t_{CSIVW1}$  (ns) = 4.477ns at or below 67 MHz CK frequency.
7. Measured at die pad.

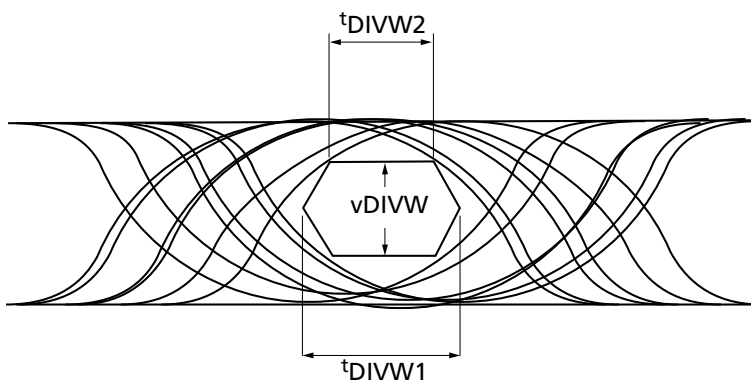
## DQ Rx Mask and Single Input Pulse Relaxed Specifications

Table 6: DQ Rx Mask and Single Input Pulse Specifications

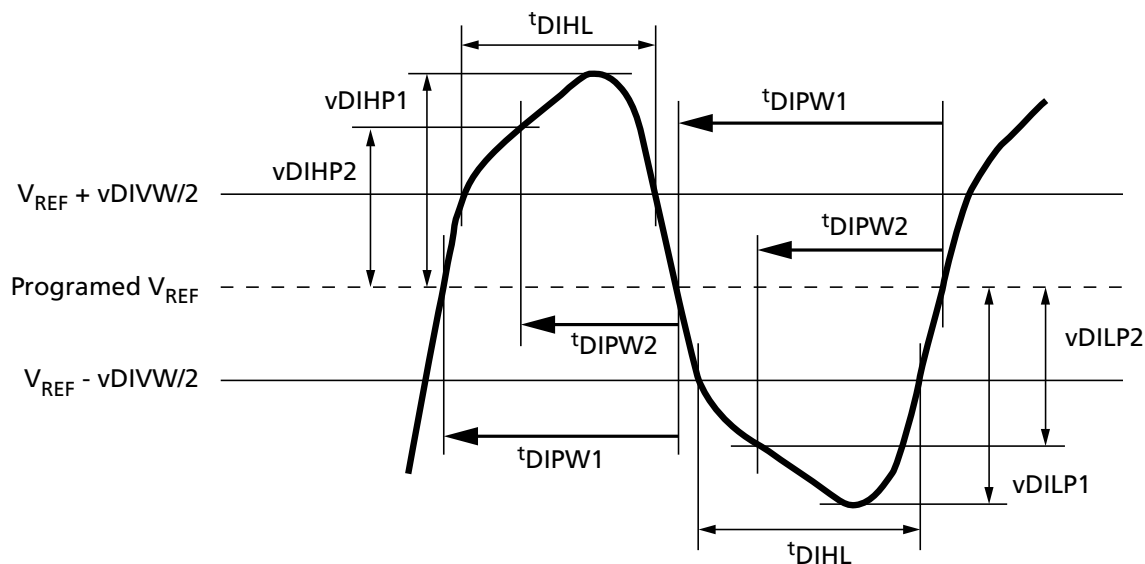
| Item                                                      | Symbol      | Min/<br>Max | WCK Frequency<br>(MHz) |      | Unit | Notes   |
|-----------------------------------------------------------|-------------|-------------|------------------------|------|------|---------|
|                                                           |             |             | 4266                   | 4800 |      |         |
| DQ Rx mask height                                         | vDIVW       | Max         | 70                     |      | mV   | 1, 2, 3 |
| DQ Rx mask width at $V_{REF(DQ)}$                         | $t_{DIVW1}$ | Max         | 0.35                   |      | UI   | 1, 3    |
| DQ Rx mask width at vDIVW                                 | $t_{DIVW2}$ | Max         | 0.18                   |      | UI   | 1, 3    |
| DQ Rx pulse width at $V_{REF(DQ)}$                        | $t_{DIPW1}$ | Min         | 0.51                   |      | UI   | 4       |
| DQ Rx pulse reference                                     | $t_{DIPW2}$ | Min         | 0.26                   |      | UI   | 4       |
| DQ Rx pulse width at $V_{REF(DQ)} \pm vDIVW/2$            | $t_{DIHL}$  | Min         | 0.24                   |      | UI   | 4       |
| DQ Rx pulse amplitude from programmed $V_{REF(DQ)}$       | vDIHP1      | Min         | 70                     |      | mV   |         |
|                                                           | vDILP1      | Max         | -70                    |      | mV   |         |
| DQ Rx early pulse amplitude from programmed $V_{REF(DQ)}$ | vDIHP2      | Min         | 55                     |      | mV   |         |
|                                                           | vDILP2      | Max         | -55                    |      | mV   |         |

- Notes: 1. Data Rx mask voltage and timing parameters are applied per pin and include the DRAM DQ-to-DQS voltage AC noise impact for frequencies greater than TBD MHz and maximum voltage of TBD mV peak-to-peak from DC-TBD MHz at a fixed temperature on the package. The voltage supply noise must comply with the component min/max DC operating conditions.
2. Rx mask voltage vDIVW must be centered around  $V_{REF(DQ)}$ .
3. Mask specifications ( $t_{DIVW1}$ ,  $t_{DIVW2}$ , and vDIVW) are the same regardless DFE enabled or disabled. DFE coefficient can be included as part of input waveform amplitude when DFE is enabled.
4. UI =  $t_{WCK}/2$ , programed  $V_{REF}$ , is defined as a percentage of MR14/15 code x  $V_{DDQ}$ .

Figure 2: DQ Rx Mask Definition



**Figure 3: LPDDR5X DQ Single Pulse Definition**



Note: 1.  $vDIHL\_AC/2 = vDIHP1 = vDILP1$ . Programed  $V_{REF(DQ)}$  is defined as percentage of MR14/15 code \*  $V_{DDQ}$ .

## DQ Rx Mask and Single Input Pulse Relaxed Specifications 3200 MHz

Table 7: DQ, DMI, Parity and DBI Rx Mask and Single Input Pulse Specifications

| Item                                                      | Symbol        | Min/Max | WCK Frequency (MHz) | Unit | Notes      |
|-----------------------------------------------------------|---------------|---------|---------------------|------|------------|
|                                                           |               |         | 3200                |      |            |
| DQ Rx mask height                                         | vDIVW         | Max     | 70                  | mV   | 1, 2, 3, 6 |
| DQ Rx mask width at $V_{REF(DQ)}$                         | $t^{DIVW1}$   | Max     | 0.35                | UI   | 1, 3       |
| DQ Rx mask width at vDIVW                                 | $t^{DIVW2}$   | Max     | 0.18                | UI   | 1, 3       |
| DQ Rx pulse width at $V_{REF(DQ)}$                        | $t^{DIPW1}$   | Min     | 0.51                | UI   | 4, 6       |
| DQ Rx pulse reference                                     | $t^{DIPW2}$   | Min     | 0.26                | UI   | 4          |
| DQ Rx pulse width at $V_{REF(DQ)} \pm vDIVW/2$            | $t^{DIHL}$    | Min     | 0.24                | UI   | 4, 6       |
| DQ Rx pulse amplitude from programmed $V_{REF(DQ)}$       | vDIHP1        | Min     | 70                  | mV   |            |
|                                                           | vDILP1        | Max     | -70                 | mV   |            |
| DQ Rx early pulse amplitude from programmed $V_{REF(DQ)}$ | vDIHP2        | Min     | 55                  | mV   |            |
|                                                           | vDILP2        | Max     | -55                 | mV   |            |
| DQ $V_{REF}$                                              | $V_{REF(DQ)}$ | Min     | 75                  | mV   | 6          |
|                                                           |               | Max     | 180                 | mV   | 6          |
| DQ to DQ offset                                           | $t^{DQ2DQ}$   | Max     | 30                  | ps   | 5          |

- Notes: 1. Data Rx mask voltage and timing parameters are applied per pin and include the DRAM DQ-to-DQS voltage AC noise impact for frequencies greater than TBD MHz and maximum voltage of TBD mV peak-to-peak from DC-TBD MHz at a fixed temperature on the package. The voltage supply noise must comply with the component min/max DC operating conditions.
2. Rx mask voltage vDIVW must be centered around  $V_{REF(DQ)}$ .
3. Mask specifications ( $t^{DIVW1}$ ,  $t^{DIVW2}$ , and vDIVW) are the same regardless DFE enabled or disabled. DFE coefficient can be included as part of input waveform amplitude when DFE is enabled.
4. UI =  $t^{WCK}/2$ , programed  $V_{REF}$ , is defined as a percentage of MR14/15 code x  $V_{DDQ}$ .
5. DQ to DQ offset defined within byte from DRAM pin to DRAM internal latch for a given component.
6. When vDIVW is 70mV or more and less than 80mV.

## 16-Bank Extended Frequency

### 16-Bank Extended Frequency Description

Micron's LPDDR5 SDRAM device which are marked with 8533 Mb/s per-pin (-023) capability can support frequency set points using 2:1 WCK to CK ratio and above the 1600 MHz limit. Shown in the table below is specification requirements when considering 1867 MHz and 2133 MHz frequencies. This support is not available on 1-alpha process node and earlier Device ID's, this feature can expand capabilities of your system.

**Table 8: 16-Bank Operation<sup>1</sup> @ 4.3 Gb/s**

| Parameter                                  | 3733 Mb/s per-pin                | Comments                           | 4267 Mb/s per-pin                | Comments                           |
|--------------------------------------------|----------------------------------|------------------------------------|----------------------------------|------------------------------------|
| RL Set 1/2/3                               | 20/22/24                         | MR2[3:0] = 1100                    | 23/25/26                         | MR2[3:0] = 1101                    |
| nRBTP                                      | 6                                |                                    | 6                                |                                    |
| WL Set A/B                                 | 11/19                            | MR1[7:4] = 1100                    | 12/22                            | MR1[7:4] = 1101                    |
| nWR x16/x8                                 | 32/34                            | MR2[7:4] = 1100                    | 37/39                            | MR2[7:4] = 1101                    |
| <sup>t</sup> WCKPRE_static <sup>2</sup>    | 5                                | Follows 7500 data rate             | 6                                | Follows 8533 data rate             |
| <sup>t</sup> WCKPRE_WR_toggle              | 4                                | Follows 3200 data rate             | 4                                | Follows 3200 data rate             |
| <sup>t</sup> WCKPRE_RD_toggle              | 10                               | Follows 3200 data rate             | 10                               | Follows 3200 data rate             |
| <sup>t</sup> WCKENL_FS                     | 2                                | Follows 3200 data rate             | 2                                | Follows 3200 data rate             |
| <sup>t</sup> WCKPRE_toggle_FS <sup>3</sup> | 14                               | Minimum                            | 16                               | Minimum                            |
| ODTLon                                     | WL - 4                           | Follows 3200 data rate             | WL - 4                           | Follows 3200 data rate             |
| ODTLoff <sup>4</sup>                       | WL + 5 (BL16),<br>WL + 9 (BL32)  | Follows 3200                       | WL + 5 (BL16),<br>WL + 9 (BL32)  | Follows 3200 data rate             |
| ODTLoff_RD_DQ                              | RL - 4                           | Follows 3200 data rate             | RL - 4                           | Follows 3200 data rate             |
| ODTLoff_RD_RDQS                            | RL - 6                           | MR10 OP[1, 5:4]<br>= 000, 001, 010 | RL - 6                           | MR10 OP[1, 5:4]<br>= 000, 001, 010 |
|                                            | RL - 8                           | MR10 OP[1, 5:4]<br>= 011, 1XX      | RL - 8                           | MR10 OP[1, 5:4]<br>= 011, 1XX      |
| ODTLon_RD_DQ <sup>5</sup>                  | RL + 6 (BL16),<br>RL + 10 (BL32) |                                    | RL + 6 (BL16),<br>RL + 10 (BL32) |                                    |
| ODTLon_RD_RDQS <sup>6</sup>                | RL + 8 (BL16),<br>RL + 12 (BL32) |                                    | RL + 8 (BL16),<br>RL + 12 (BL32) |                                    |

Notes: 1. Restricted to WCK:CK 2:1 ratio, WCK:CK 4:1 ratio not supported; Link ECC is disabled, and DVFSC/E-DVFSC is disabled.

2. Common for WR/RD/FS.

3. Minimum 1 + RL - (<sup>t</sup>WCKENL\_FS + <sup>t</sup>WCKPRE\_Static) when CAS to RD is 1CK.

4. (WL + BL/n\_min + RU(<sup>t</sup>WCK2DQI(max)/<sup>t</sup>CK)).

5. (RL + BL/n\_min + RU(<sup>t</sup>WCK2DQO(max)/<sup>t</sup>CK)).

6. (RL + BL/n\_min + RU(<sup>t</sup>WCK2DQO(max)/<sup>t</sup>CK)) + 2.

7. 8533 MT/s or higher data rated parts support 16-bank mode up to 4267 MT/s with restrictions, all other speed rated parts greater than 3200 MT/s per-pin and less than 8533 MT/s per-pin are restricted from the extended 16B mode capabilities. Refer to the above table for constraints for operating in 16-bank mode when data rate is greater than 3200 MT/s per-pin and equal to or less than 4267 MT/s per-pin.

8. When operating in the 16-bank mode, the FSP procedure must be used when setting the data rate above 3.2 Gb/s per-pin even when setting for the first time. For example, if the device is powered-up and initialized for 4266 Gb/s per-pin timing at the initial operation start, the FSP procedure must still be used. See [Figure 4: 16B and BG Data Rate Change Flow Chart Showing Extended Capabilities](#) on page 17 for details of FSP usage.

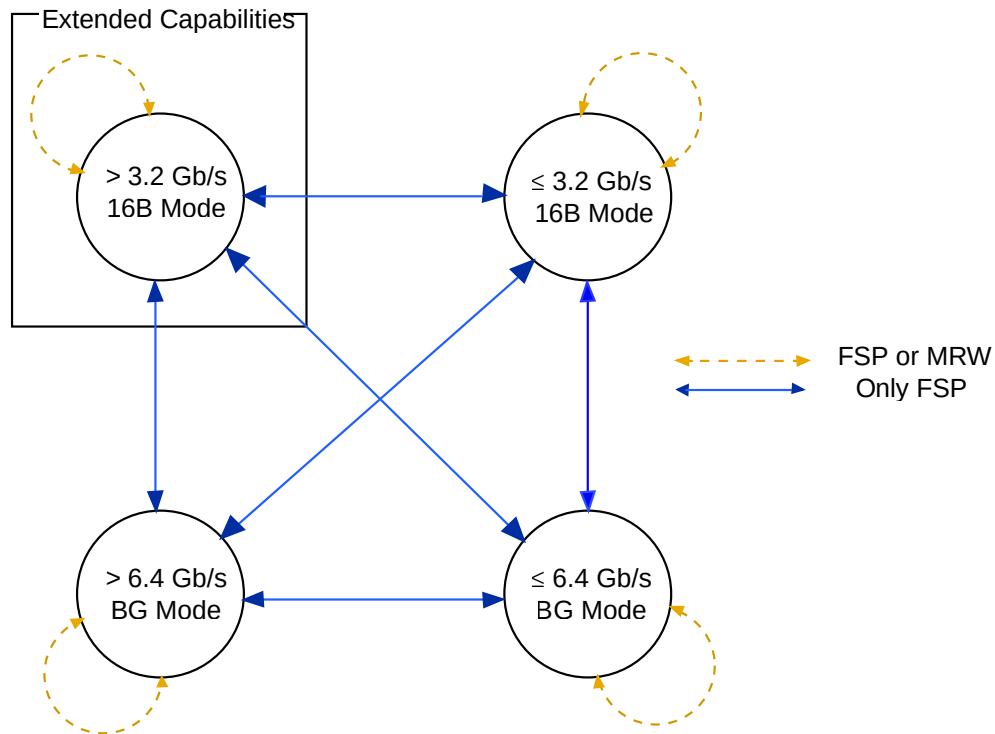


## 16B/BG Data Rate Change Diagram With FSP Requirements

The following flow chart diagram shows the needed 16-bank (16B) and bank group (BG) data rate change details and how the frequency set protocol (FSP) supports the extended frequency range.

The diagram below represents the device extended capabilities which are extended to 4267 Mb/s per-pin data rate in 16B mode.

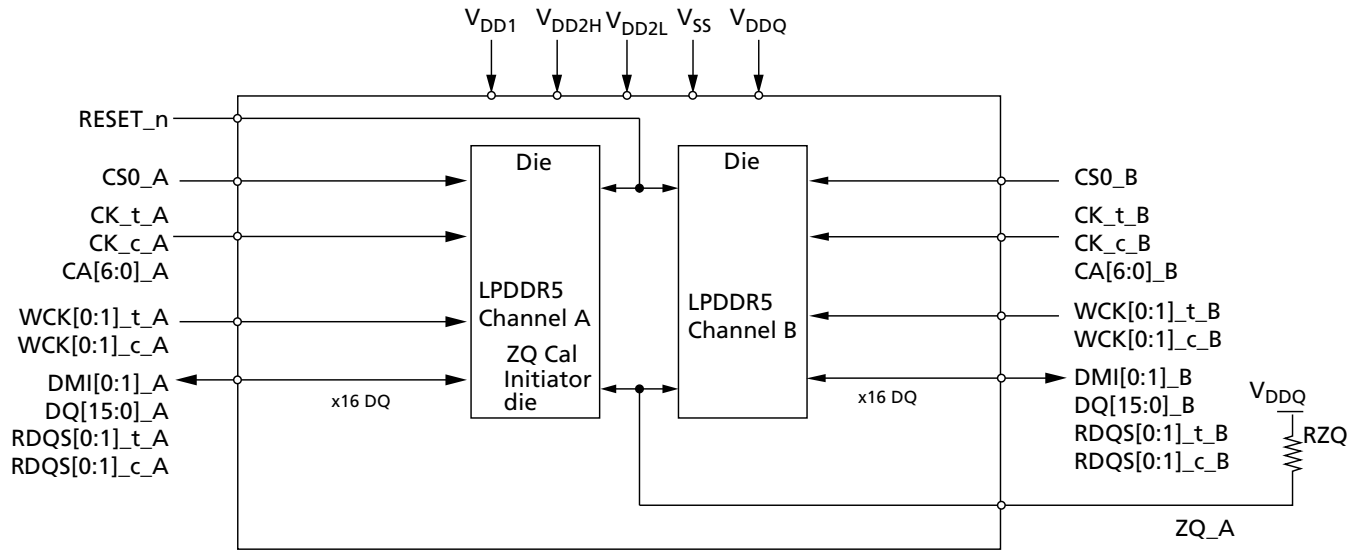
**Figure 4: 16B and BG Data Rate Change Flow Chart Showing Extended Capabilities**



## Package Block Diagrams

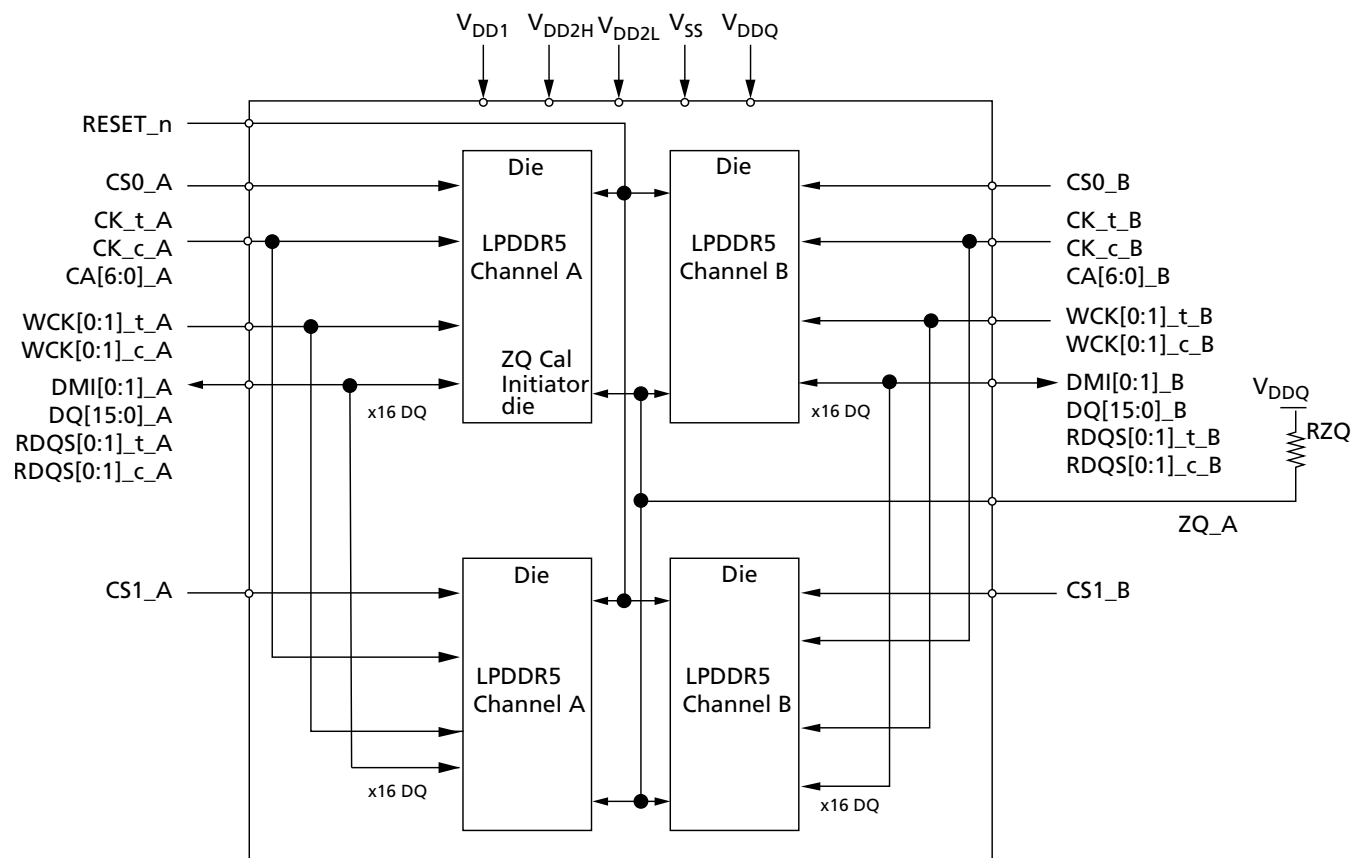
### Dual Die, Dual Channel, Single Rank

**Figure 5: Dual-Die, Dual-Channel, Single-Rank Package Block Diagram**



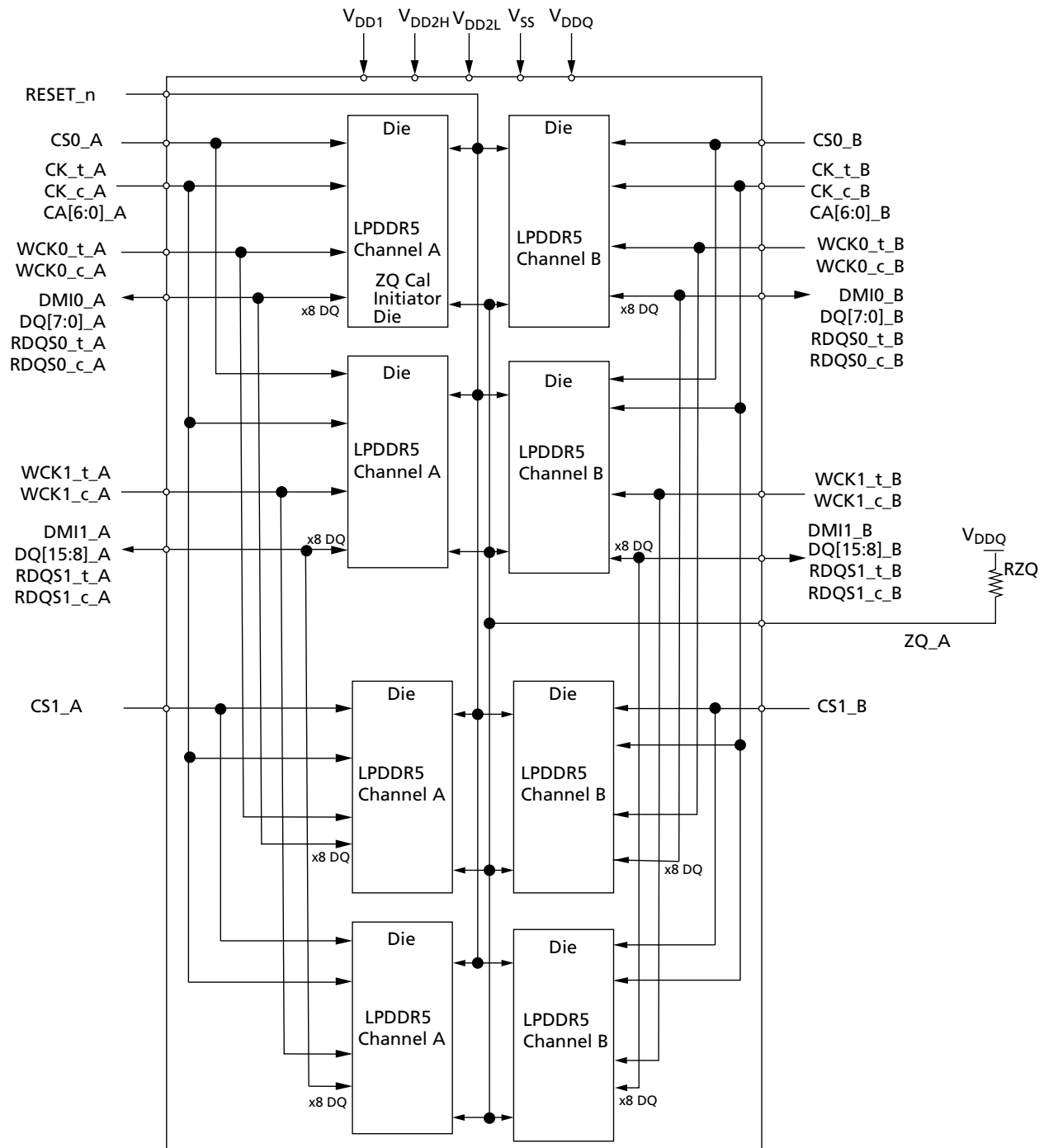
## Quad Die, Dual Channel, Dual Rank

Figure 6: Quad-Die, Dual-Channel, Dual-Rank Package Block Diagram



## Eight Die, Dual Channel, Dual Rank

Figure 7: Eight-Die, Dual-Channel, Dual-Rank Package Block Diagram



## Ball Assignments and Descriptions

### 315b Dual Channel, 1 Rank, 2 Rank

**Table 9: 315-Ball/Pad Descriptions**

| Symbol                                                                         | Type          | Description                                                                                                                                                                                                                                                                                                                                                                                                                     |
|--------------------------------------------------------------------------------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CK_t_[A:B],<br>CK_c_[A:B]                                                      | Input         | <b>Clock:</b> CK_t and CK_c are differential clock inputs. All double data rate (DDR) command/address inputs are sampled on both crossing points of CK_t and CK_c. The first crossing point is the rising (falling) edge of CK_t (CK_c) and second crossing point is falling (rising) edge of CK_t (CK_c). Single data rate (SDR) inputs, CS is sampled on the crossing point that is the rising (falling) edge of CK_t (CK_c). |
| CS0_[A:B], CS1_[A:B]                                                           | Input         | <b>Chip select:</b> CS is part of the command code, and is sampled on the rising (falling) edge of CK_t (CK_c) unless the device is in power-down or deep sleep mode where it becomes an asynchronous signal. Each rank (0, 1) has its own CS signals. CS1_[A:B] become NC pins in a single-rank package.                                                                                                                       |
| CA[6:0]_[A:B]                                                                  | Input         | <b>Command/address inputs:</b> Provide the command and address inputs according to the command truth table.                                                                                                                                                                                                                                                                                                                     |
| WCK[1:0]_t_[A:B],<br>WCK[1:0]_c_[A:B]                                          | Input         | <b>Data clock:</b> WCK_t and WCK_c are differential clock inputs used for write data capture and read data output.                                                                                                                                                                                                                                                                                                              |
| DQ[15:0]_[A:B]                                                                 | I/O           | <b>Data input/output:</b> Bidirectional data bus.                                                                                                                                                                                                                                                                                                                                                                               |
| RDQS[1:0]_t_[A:B],<br>RDQS[1:0]_c_[A:B]                                        | I/O<br>Output | <b>Read data strobe:</b> RDQS_t and RDQS_c are differential output clock signals used to strobe data during a READ operation. RDQS_t is also used as a parity pin during write link protection enabled. Each byte of data has RDQS_t and RDQS_c signals.                                                                                                                                                                        |
| DMI[1:0]_[A:B]                                                                 | I/O           | <b>Data mask inversion:</b> DMI serves multiple functions such as data mask (DM), data bus inversion (DBI), and parity at READ with ECC operation by setting the mode register. DMI is a bidirectional signal and each byte of data has a DMI signal.                                                                                                                                                                           |
| ZQ_A                                                                           | Reference     | <b>ZQ calibration reference:</b> Used to calibrate the output drive strength and the termination resistance. The ZQ pin should be connected to V <sub>DDQ</sub> through a 240 ohm $\pm 1\%$ resistor.                                                                                                                                                                                                                           |
| V <sub>DDQ</sub> , V <sub>DD1</sub> , V <sub>DD2H</sub> ,<br>V <sub>DD2L</sub> | Supply        | <b>Power supplies:</b> Isolated on the die for improved noise immunity.                                                                                                                                                                                                                                                                                                                                                         |
| V <sub>SS</sub>                                                                | Supply        | <b>Ground reference:</b> Power supply ground reference.                                                                                                                                                                                                                                                                                                                                                                         |
| RESET_n                                                                        | Input         | <b>Reset:</b> When asserted LOW, the RESET pin resets the die. Reset is an asynchronous signal.                                                                                                                                                                                                                                                                                                                                 |
| NC                                                                             | –             | <b>No connect:</b> Not internally connected.                                                                                                                                                                                                                                                                                                                                                                                    |
| RFU                                                                            | –             | <b>Reserved Future Use:</b> Not internally connected.                                                                                                                                                                                                                                                                                                                                                                           |

**Figure 8: 315-Ball Dual-Channel Discrete FBGA**

|    | 1                 | 2                 | 3                 | 4                 | 5                 | 6                 | 7                 | 8                 | 9                 | 10                | 11                | 12                | 13                | 14                | 15                |    |
|----|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|-------------------|----|
| A  | NC                | NC                | V <sub>DDQ</sub>  | DMIO_A            | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2L</sub> | V <sub>SS</sub>   | DMIO_A            | V <sub>DDQ</sub>  | NC                | NC                | A  |
| B  | NC                | V <sub>DDQ</sub>  | RDQS0_t_A         | V <sub>SS</sub>   | DQ4_A             | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2L</sub> | DQ12_A            | V <sub>SS</sub>   | RDQS1_t_A         | V <sub>DDQ</sub>  | NC                | B  |
| C  | V <sub>DD1</sub>  | DQ1_A             | V <sub>DDQ</sub>  | RDQS0_c_A         | V <sub>SS</sub>   | DQ5_A             | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ13_A            | V <sub>SS</sub>   | RDQS1_c_A         | V <sub>DDQ</sub>  | DQ9_A             | V <sub>DD1</sub>  | C  |
| D  | DQ0_A             | V <sub>SS</sub>   | DQ3_A             | V <sub>DDQ</sub>  | WCK0_c_A          | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | WCK1_c_A          | V <sub>DDQ</sub>  | DQ11_A            | V <sub>SS</sub>   | DQ8_A             | D  |
| E  | V <sub>SS</sub>   | DQ2_A             | V <sub>SS</sub>   | WCK0_t_A          | V <sub>DDQ</sub>  | DQ6_A             | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ14_A            | V <sub>DDQ</sub>  | WCK1_t_A          | V <sub>SS</sub>   | DQ10_A            | V <sub>SS</sub>   | E  |
| F  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | DQ7_A             | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | DQ15_A            | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | F  |
| G  | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | CA0_A             | V <sub>SS</sub>   | CS1_A             | V <sub>SS</sub>   | CA2_A             | V <sub>SS</sub>   | CA4_A             | V <sub>SS</sub>   | CA6_A             | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | G  |
| H  | RESET_N           | V <sub>DD2L</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | CA1_A             | V <sub>SS</sub>   | CS0_A             | V <sub>SS</sub>   | CK_t_A            | V <sub>SS</sub>   | CA3_A             | V <sub>SS</sub>   | CA5_A             | V <sub>DD2L</sub> | ZQ_A              | H  |
| J  | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | RFU               | V <sub>DD2H</sub> | RFU               | V <sub>SS</sub>   | V <sub>SS</sub>   | CK_c_A            | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | J  |
| K  | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | K  |
| L  | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | L  |
| M  | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | M  |
| N  | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | CK_c_B            | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>SS</sub>   | N  |
| P  | RFU               | V <sub>DD2L</sub> | CA5_B             | V <sub>SS</sub>   | CA3_B             | V <sub>SS</sub>   | CK_t_B            | V <sub>SS</sub>   | CS0_B             | V <sub>SS</sub>   | CA1_B             | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2L</sub> | RFU               | P  |
| R  | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | CA6_B             | V <sub>SS</sub>   | CA4_B             | V <sub>SS</sub>   | CA2_B             | V <sub>SS</sub>   | CS1_B             | V <sub>SS</sub>   | CA0_B             | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | R  |
| T  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | DQ15_B            | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2H</sub> | DQ7_B             | V <sub>DDQ</sub>  | V <sub>DDQ</sub>  | V <sub>SS</sub>   | V <sub>DDQ</sub>  | T  |
| U  | V <sub>SS</sub>   | DQ10_B            | V <sub>SS</sub>   | WCK1_t_B          | V <sub>DDQ</sub>  | DQ14_B            | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ6_B             | V <sub>DDQ</sub>  | WCK0_t_B          | V <sub>SS</sub>   | DQ2_B             | V <sub>SS</sub>   | U  |
| V  | DQ8_B             | V <sub>SS</sub>   | DQ11_B            | V <sub>DDQ</sub>  | WCK1_c_B          | V <sub>SS</sub>   | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>SS</sub>   | WCK0_c_B          | V <sub>DDQ</sub>  | DQ3_B             | V <sub>SS</sub>   | DQ0_B             | V  |
| W  | V <sub>DD1</sub>  | DQ9_B             | V <sub>DDQ</sub>  | RDQS1_c_B         | V <sub>SS</sub>   | DQ13_B            | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | DQ5_B             | V <sub>SS</sub>   | RDQS0_c_B         | V <sub>DDQ</sub>  | DQ1_B             | V <sub>DD1</sub>  | W  |
| Y  | NC                | V <sub>DDQ</sub>  | RDQS1_t_B         | V <sub>SS</sub>   | DQ12_B            | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>SS</sub>   | V <sub>DD2H</sub> | V <sub>DD2L</sub> | DQ4_B             | V <sub>SS</sub>   | RDQS0_t_B         | V <sub>DDQ</sub>  | NC                | Y  |
| AA | NC                | NC                | V <sub>DDQ</sub>  | DMIO_B            | V <sub>SS</sub>   | V <sub>DD2L</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2H</sub> | V <sub>DD2L</sub> | V <sub>SS</sub>   | DMIO_B            | V <sub>DDQ</sub>  | NC                | NC                | AA |
|    | 1                 | 2                 | 3                 | 4                 | 5                 | 6                 | 7                 | 8                 | 9                 | 10                | 11                | 12                | 13                | 14                | 15                |    |

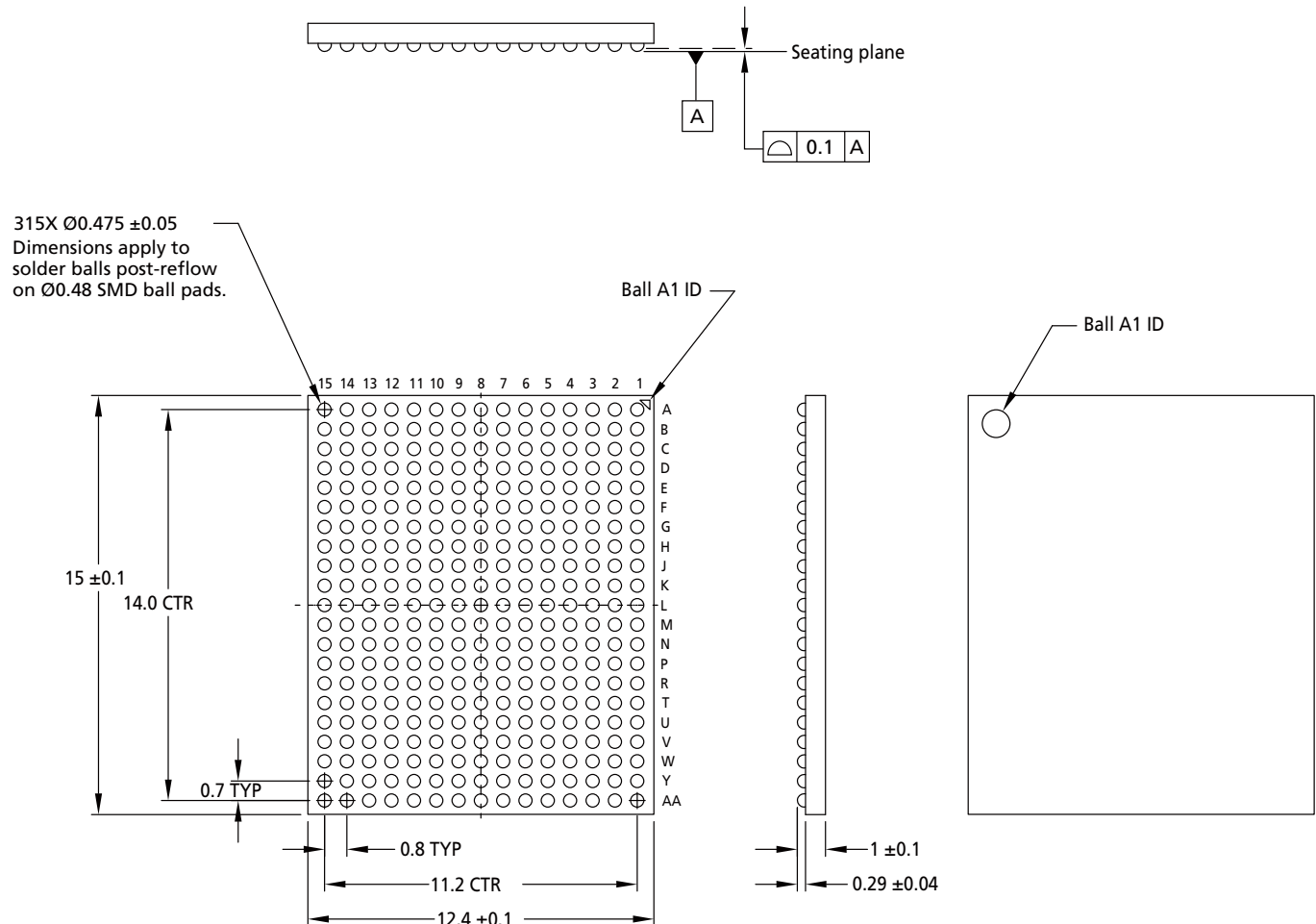
Top View (ball down)

V<sub>SS</sub>
V<sub>DD1</sub>
V<sub>DD2H</sub>
V<sub>DD2L</sub>
V<sub>DDQ</sub>
CK
RDQS
WCK
DQ,DMI
CA, CS, ZQ, RESET
NC, RFU

## Package Dimensions

### 315-Ball Package (Package Code: DS)

**Figure 9: 315-Ball TFBGA – 12.4mm (TYP) × 15.0mm (TYP) × 1.1mm (MAX) (Package Code: DS)**

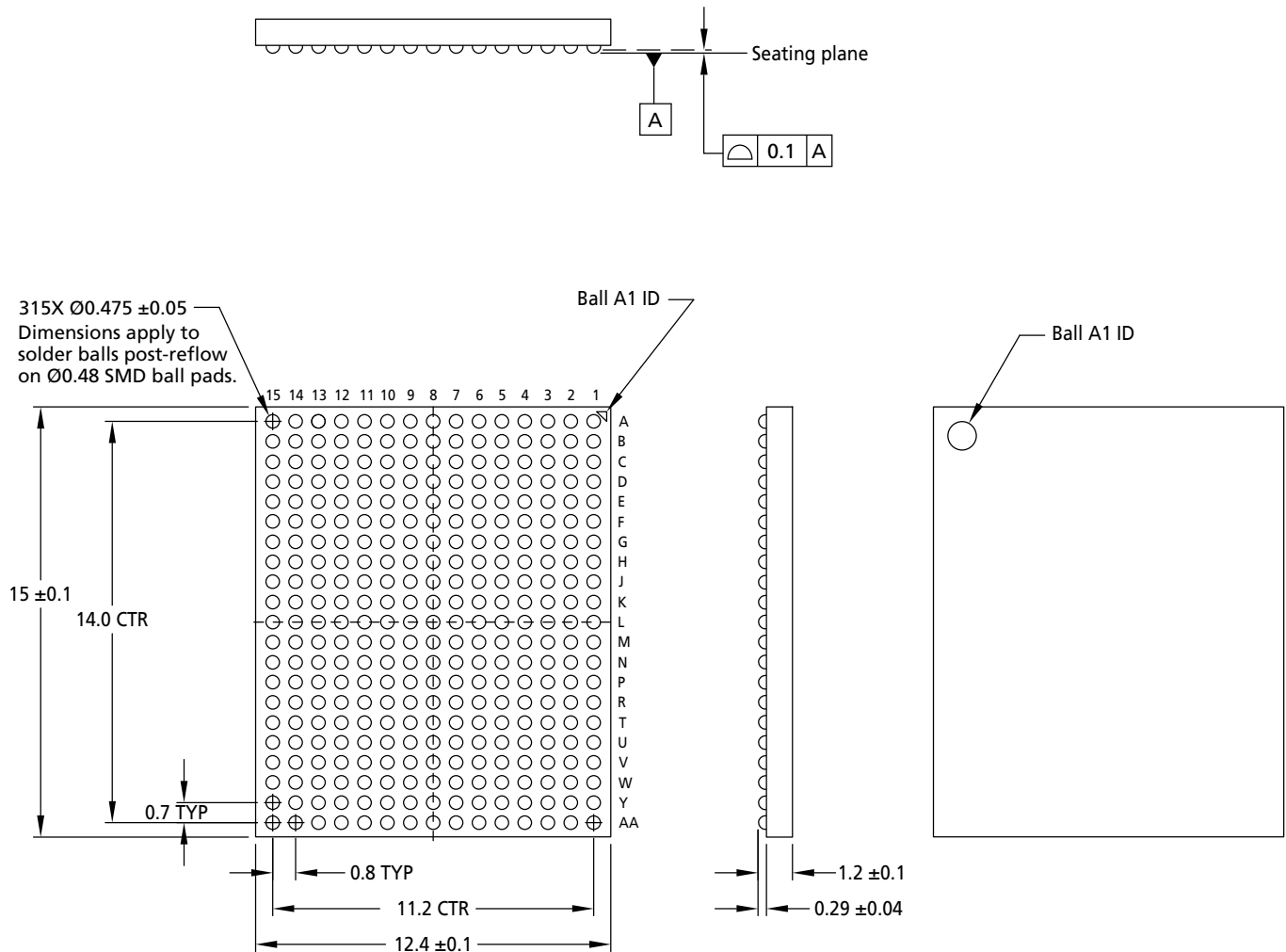


Notes: 1. All dimensions are in millimeters.

2. Solder ball composition: SACQ with CuOSP pads (Sn-4Ag-0.5Cu-3Bi-0.05Ni).

# 315-Ball Package (Package Code: DV)

Figure 10: 315-Ball LFBGA – 12.4mm (TYP) × 15.0mm (TYP) × 1.3mm (MAX) (Package Code: DV)



- Notes: 1. All dimensions are in millimeters.  
2. Solder ball composition: SACQ with CuOSP pads (Sn-4Ag-0.5Cu-3Bi-0.05Ni).





Package Thermal Impedance

Table 10: Package Thermal Impedance Characteristics

| Die Revision | Package                           | Parameter              | Symbol        | Value | Unit |
|--------------|-----------------------------------|------------------------|---------------|-------|------|
| Rev D        | 315-ball, DDP,<br>package code DS | Junction-to-case (TOP) | $\Theta_{JC}$ | 3.3   | °C/W |
|              |                                   | Junction-to-board      | $\Theta_{JB}$ | 10.1  | °C/W |
|              | 315-ball, QDP,<br>package code DS | Junction-to-case (TOP) | $\Theta_{JC}$ | 2.5   | °C/W |
|              |                                   | Junction-to-board      | $\Theta_{JB}$ | 8.3   | °C/W |
|              | 315-ball, 8DP,<br>package code DV | Junction-to-case (TOP) | $\Theta_{JC}$ | 2.4   | °C/W |
|              |                                   | Junction-to-board      | $\Theta_{JB}$ | 10.0  | °C/W |

## Product-Specific Mode Register Definition

**Table 11: Mode Register Contents**

| Mode Register | OP7                                                                                                                 | OP6          | OP5                          | OP4                            | OP3                    | OP2                         | OP1                                            | OP0                |
|---------------|---------------------------------------------------------------------------------------------------------------------|--------------|------------------------------|--------------------------------|------------------------|-----------------------------|------------------------------------------------|--------------------|
| MR0           | Per-pin DFE                                                                                                         | Pre Emphasis | Unified NT ODT behavior mode | DMI output behavior mode       | Optimized refresh mode | Enhanced WCK always-on mode | Latency mode                                   | NT ODT timing mode |
|               | OP[0] = 1b: Device supports different NT ODT latency for DQ and RDQS                                                |              |                              |                                |                        |                             |                                                |                    |
|               | OP[1] = 0b: Device supports x16 mode latency for 1G32, 2G32<br>OP[1] = 1b: Device supports x8 mode latency for 4G32 |              |                              |                                |                        |                             |                                                |                    |
|               | OP[2] = 1b: Device supports enhanced WCK always-on mode                                                             |              |                              |                                |                        |                             |                                                |                    |
|               | OP[3] = 1b: Device supports optimized refresh mode                                                                  |              |                              |                                |                        |                             |                                                |                    |
|               | OP[4] = 1b: Device supports both DMI behavior mode 1 and 2 and mode selection                                       |              |                              |                                |                        |                             |                                                |                    |
|               | OP[5] = 1b: The NT ODT behavior follows the unified NT ODT behavior                                                 |              |                              |                                |                        |                             |                                                |                    |
|               | OP[6] = 1b: Device supports Pre Emphasis mode                                                                       |              |                              |                                |                        |                             |                                                |                    |
|               | OP[7] = 1b: Device supports Per Pin DFE                                                                             |              |                              |                                |                        |                             |                                                |                    |
| MR1           |                                                                                                                     |              |                              |                                |                        | DRFM support <sup>3</sup>   | ARFM support <sup>3</sup>                      | CS ODT OP support  |
|               | OP[0] = 1b: Device supports CS ODT behavior OP                                                                      |              |                              |                                |                        |                             |                                                |                    |
|               | OP[1] = 1b: Device supports ARFM                                                                                    |              |                              |                                |                        |                             |                                                |                    |
|               | OP[2] = 1b: Device supports DRFM                                                                                    |              |                              |                                |                        |                             |                                                |                    |
| MR3           |                                                                                                                     |              |                              | BK/BG ORG                      |                        |                             |                                                |                    |
|               | OP[4:3] = 00b: BG, 10b: 16B Mode support                                                                            |              |                              |                                |                        |                             |                                                |                    |
| MR4           |                                                                                                                     |              |                              | Refresh Multiplier (Note 6, 7) |                        |                             |                                                |                    |
|               | OP[4:0]: Refer to General LPDDR5/LPDDR5X Specification 1 for mode register definitions.                             |              |                              |                                |                        |                             |                                                |                    |
| MR5           | Manufacturer ID                                                                                                     |              |                              |                                |                        |                             |                                                |                    |
|               | 1111 1111b: Micron                                                                                                  |              |                              |                                |                        |                             |                                                |                    |
| MR6           | Revision ID1                                                                                                        |              |                              |                                |                        |                             |                                                |                    |
|               | 0000 1001b                                                                                                          |              |                              |                                |                        |                             |                                                |                    |
| MR8           | I/O width                                                                                                           |              | Density                      |                                |                        |                             | Device Type <sup>5</sup>                       |                    |
|               | OP[7:6] = 00b: x16 for 1G32, 2G32<br>OP[7:6] = 01b: x8 for 4G32                                                     |              | OP[5:2] = 0110b: 16Gb        |                                |                        |                             | OP[1:0] = 10b: LPDDR5X SDRAM (up to 9600 Mb/s) |                    |
|               |                                                                                                                     |              |                              |                                |                        |                             |                                                |                    |
| MR19          |                                                                                                                     |              | WCK2DQ OSC FM                |                                |                        |                             |                                                |                    |
|               | OP[5] = 1b: WCK2DQ OSC FM supported                                                                                 |              |                              |                                |                        |                             |                                                |                    |
| MR21          | WXS                                                                                                                 |              |                              |                                | ODTD-CSFS              | WXFS                        | RDCFS                                          | WDCFS              |
|               | OP[0] = 1b: WRITE DATA COPY function supported                                                                      |              |                              |                                |                        |                             |                                                |                    |
|               | OP[1] = 1b: READ DATA COPY function supported                                                                       |              |                              |                                |                        |                             |                                                |                    |
|               | OP[2] = 1b: WRITE X function supported                                                                              |              |                              |                                |                        |                             |                                                |                    |
|               | OP[3] = 1b: Device ODTD-CS is supported                                                                             |              |                              |                                |                        |                             |                                                |                    |
|               | OP[7] = 1b: Data to be written can be selected with 0 and 1                                                         |              |                              |                                |                        |                             |                                                |                    |

**Table 11: Mode Register Contents (Continued)**

| Mode Register             | OP7                                                                                                                     | OP6       | OP5    | OP4 | OP3        | OP2                  | OP1    | OP0  |
|---------------------------|-------------------------------------------------------------------------------------------------------------------------|-----------|--------|-----|------------|----------------------|--------|------|
| MR24                      | DFES                                                                                                                    |           |        |     | Read DCA   |                      |        |      |
|                           | OP[3] = 1b: Device supports Read DCA                                                                                    |           |        |     |            |                      |        |      |
|                           | OP[7] = 1b: Device supports DFE (See Note 4)                                                                            |           |        |     |            |                      |        |      |
| MR26                      |                                                                                                                         | RDQSTFS   |        |     |            |                      |        |      |
|                           | OP[6] = 1b: Read/write-based RDQS_t TRAINING function supported                                                         |           |        |     |            |                      |        |      |
| MR27                      | RAAMULT                                                                                                                 |           | RAAIMT |     |            |                      |        | RFM  |
|                           | OP[0] = 1b: RFM is required                                                                                             |           |        |     |            |                      |        |      |
|                           | OP[5:1] = 01000b: 64                                                                                                    |           |        |     |            |                      |        |      |
|                           | OP[7:6] = 01b: 4X                                                                                                       |           |        |     |            |                      |        |      |
| MR41                      |                                                                                                                         |           |        |     | E-DVFS ODT | DVFS/ E-DVFS Support |        |      |
|                           | OP[2:1] = 01b: Only Enhanced DVFS Mode supported                                                                        |           |        |     |            |                      |        |      |
|                           | OP[3] = 0b: Enhanced DVFS ODT option not supported                                                                      |           |        |     |            |                      |        |      |
| MR43                      |                                                                                                                         | SBEC rule |        |     |            |                      |        |      |
|                           | OP[6] = 1b: Simultaneous SBE on each DQ byte and DMI are independently counted                                          |           |        |     |            |                      |        |      |
| MR57                      |                                                                                                                         |           |        |     | RFMSB      |                      | RAADEC |      |
|                           | OP[1:0] = 10b: 2 × RAAIMT                                                                                               |           |        |     |            |                      |        |      |
|                           | OP[3:2] = 01b: Single Bank Mode supported                                                                               |           |        |     |            |                      |        |      |
| MR75                      |                                                                                                                         |           |        |     |            |                      |        | BRCS |
|                           | OP[0] = 1b: BRC is supported                                                                                            |           |        |     |            |                      |        |      |
| MR63 - MR74, MR76 - MR164 | Reserved MR bits MR63 through MR74 and MR76 through MR164 are RFU by JEDEC standard and should not be accessed by user. |           |        |     |            |                      |        |      |

- Notes: 1. The contents of mode registers described here reflect information specific to each die in these packages.  
2. Refer to General LPDDR5/LPDDR5X Specification 1 for mode registers not described here.  
3. Refer to General LPDDR5/LPDDR5X Specification 3 for feature description not described here.  
4. Device supports 7-step DFE.  
5. Device type only supports bank group and 16B modes.  
6. MR4 OP[4:0] output from each die in a defined package shall be used to determine the required package level refresh rate. Any other method used to determine a valid refresh rate, places ownership and responsibility of the correct refresh rate on the system developer or end user. T<sub>OPER</sub> (case surface temperature) shall be used to determine whether operating temperature requirements are being met. Any other method used to determine operating temperature, places ownership and responsibility of the correct operating temperature on the system developer or end user.  
7. The intent of a MR4 OP[4:0] output of <01111> is to not to support a refresh rate of 0.125xd; rather a method to inform the host the die temperature is most likely being operated beyond its supported upper maximum limit and the host should immediately place the DRAM in to a refresh only state at 0.125xd refresh rate until the MR4 readout of <01111> no longer exists. No other operation other than refresh should be conducted.

## I<sub>DD</sub> Parameters

Refer to I<sub>DD</sub> Specification Parameters and Test Conditions section in General LPDDR5/LPDDR5X Specifications 2 for detailed conditions.

**Table 12: I<sub>DD</sub> Parameters at 9600 Mb/s – Single Die**

| Symbol               | Supply            | x8 Mode |       |       | x16 Mode |       |       | Unit | Note |
|----------------------|-------------------|---------|-------|-------|----------|-------|-------|------|------|
|                      |                   | UT      | AT    | IT    | UT       | AT    | IT    |      |      |
| I <sub>DD01</sub>    | V <sub>DD1</sub>  | 4.40    | 4.10  | 4.10  | 4.40     | 4.10  | 4.10  | mA   |      |
| I <sub>DD02H</sub>   | V <sub>DD2H</sub> | 75.00   | 59.00 | 59.00 | 75.00    | 59.00 | 59.00 |      |      |
| I <sub>DD02L</sub>   | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD0Q</sub>    | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |
| I <sub>DD2P1</sub>   | V <sub>DD1</sub>  | 2.30    | 1.60  | 1.60  | 2.30     | 1.60  | 1.60  | mA   |      |
| I <sub>DD2P2H</sub>  | V <sub>DD2H</sub> | 7.00    | 4.80  | 4.80  | 7.00     | 4.80  | 4.80  |      |      |
| I <sub>DD2P2L</sub>  | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD2PQ</sub>   | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |
| I <sub>DD2PS1</sub>  | V <sub>DD1</sub>  | 2.30    | 1.60  | 1.60  | 2.30     | 1.60  | 1.60  | mA   |      |
| I <sub>DD2PS2H</sub> | V <sub>DD2H</sub> | 7.00    | 4.80  | 4.80  | 7.00     | 4.80  | 4.80  |      |      |
| I <sub>DD2PS2L</sub> | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD2PSQ</sub>  | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |
| I <sub>DD2N1</sub>   | V <sub>DD1</sub>  | 2.30    | 1.60  | 1.60  | 2.30     | 1.60  | 1.60  | mA   |      |
| I <sub>DD2N2H</sub>  | V <sub>DD2H</sub> | 51.50   | 42.50 | 42.50 | 52.00    | 43.00 | 43.00 |      |      |
| I <sub>DD2N2L</sub>  | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD2NQ</sub>   | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |
| I <sub>DD2NS1</sub>  | V <sub>DD1</sub>  | 2.30    | 1.60  | 1.60  | 2.30     | 1.60  | 1.60  | mA   |      |
| I <sub>DD2NS2H</sub> | V <sub>DD2H</sub> | 51.50   | 42.50 | 42.50 | 52.00    | 43.00 | 43.00 |      |      |
| I <sub>DD2NS2L</sub> | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD2NSQ</sub>  | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |
| I <sub>DD3P1</sub>   | V <sub>DD1</sub>  | 2.90    | 2.20  | 2.20  | 2.90     | 2.20  | 2.20  | mA   |      |
| I <sub>DD3P2H</sub>  | V <sub>DD2H</sub> | 33.00   | 18.00 | 18.00 | 33.00    | 18.00 | 18.00 |      |      |
| I <sub>DD3P2L</sub>  | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD3PQ</sub>   | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |
| I <sub>DD3PS1</sub>  | V <sub>DD1</sub>  | 2.90    | 2.20  | 2.20  | 2.90     | 2.20  | 2.20  | mA   |      |
| I <sub>DD3PS2H</sub> | V <sub>DD2H</sub> | 33.00   | 18.00 | 18.00 | 33.00    | 18.00 | 18.00 |      |      |
| I <sub>DD3PS2L</sub> | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD3PSQ</sub>  | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |
| I <sub>DD3N1</sub>   | V <sub>DD1</sub>  | 4.00    | 3.10  | 3.10  | 4.00     | 3.10  | 3.10  | mA   |      |
| I <sub>DD3N2H</sub>  | V <sub>DD2H</sub> | 74.00   | 50.50 | 50.50 | 75.00    | 51.00 | 51.00 |      |      |
| I <sub>DD3N2L</sub>  | V <sub>DD2L</sub> | 0.20    | 0.20  | 0.20  | 0.20     | 0.20  | 0.20  |      |      |
| I <sub>DD3NQ</sub>   | V <sub>DDQ</sub>  | 0.60    | 0.60  | 0.60  | 0.60     | 0.60  | 0.60  |      |      |

**Table 12: I<sub>DD</sub> Parameters at 9600 Mb/s – Single Die (Continued)**

| Symbol               | Supply            | x8 Mode |        |        | x16 Mode |        |        | Unit | Note    |
|----------------------|-------------------|---------|--------|--------|----------|--------|--------|------|---------|
|                      |                   | UT      | AT     | IT     | UT       | AT     | IT     |      |         |
| I <sub>DD4R1</sub>   | V <sub>DD1</sub>  | 22.00   | 21.00  | 21.00  | 24.00    | 23.00  | 23.00  | mA   | 3, 4, 6 |
| I <sub>DD4R2H</sub>  | V <sub>DD2H</sub> | 300.00  | 260.00 | 260.00 | 420.00   | 380.00 | 380.00 |      |         |
| I <sub>DD4R2L</sub>  | V <sub>DD2L</sub> | 0.20    | 0.20   | 0.20   | 0.20     | 0.20   | 0.20   |      |         |
| I <sub>DD4RQ</sub>   | V <sub>DDQ</sub>  | 69.00   | 69.00  | 69.00  | 138.00   | 138.00 | 138.00 |      |         |
| I <sub>DD4W1</sub>   | V <sub>DD1</sub>  | 20.00   | 19.00  | 19.00  | 22.00    | 21.00  | 21.00  | mA   | 3, 6    |
| I <sub>DD4W2H</sub>  | V <sub>DD2H</sub> | 235.00  | 205.00 | 205.00 | 325.00   | 295.00 | 295.00 |      |         |
| I <sub>DD4W2L</sub>  | V <sub>DD2L</sub> | 0.20    | 0.20   | 0.20   | 0.20     | 0.20   | 0.20   |      |         |
| I <sub>DD4WQ</sub>   | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |
| I <sub>DD51</sub>    | V <sub>DD1</sub>  | 22.00   | 20.00  | 20.00  | 22.00    | 20.00  | 20.00  | mA   |         |
| I <sub>DD52H</sub>   | V <sub>DD2H</sub> | 250.00  | 200.00 | 200.00 | 250.00   | 200.00 | 200.00 |      |         |
| I <sub>DD52L</sub>   | V <sub>DD2L</sub> | 0.20    | 0.20   | 0.20   | 0.20     | 0.20   | 0.20   |      |         |
| I <sub>DD5Q</sub>    | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |
| I <sub>DD5AB1</sub>  | V <sub>DD1</sub>  | 3.60    | 3.30   | 3.30   | 3.60     | 3.30   | 3.30   | mA   |         |
| I <sub>DD5AB2H</sub> | V <sub>DD2H</sub> | 75.00   | 49.00  | 49.00  | 75.00    | 50.00  | 50.00  |      |         |
| I <sub>DD5AB2L</sub> | V <sub>DD2L</sub> | 0.20    | 0.20   | 0.20   | 0.20     | 0.20   | 0.20   |      |         |
| I <sub>DD5ABQ</sub>  | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |
| I <sub>DD5PB1</sub>  | V <sub>DD1</sub>  | 3.60    | 3.30   | 3.30   | 3.60     | 3.30   | 3.30   | mA   |         |
| I <sub>DD5PB2H</sub> | V <sub>DD2H</sub> | 75.00   | 49.00  | 49.00  | 75.00    | 50.00  | 50.00  |      |         |
| I <sub>DD5PB2L</sub> | V <sub>DD2L</sub> | 0.20    | 0.20   | 0.20   | 0.20     | 0.20   | 0.20   |      |         |
| I <sub>DD5PBQ</sub>  | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |

- Notes: 1. Published I<sub>DD</sub> values except I<sub>DD4RQ</sub> are the maximum I<sub>DD</sub> values considering the worst-case conditions of process, temperature, and voltage.  
2. BG mode enabled. Enhanced DVFSC and DVFSQ disabled.  
3. BL = 16, DBI disabled.  
4. I<sub>DD4RQ</sub> value is reference only. Typical value. Output load = 5pF; R<sub>ON</sub> = 40 ohms; T<sub>C</sub> = 25°C  
5. V<sub>DD1</sub> = 1.70–1.95V; V<sub>DD2H</sub> = 1.01–1.12V; V<sub>DD2L</sub> = 0.87–0.97V; V<sub>DDQ</sub> = 0.47–0.57V (DVFSQ disabled)/0.27–0.37V (DVFSQ enabled)  
6. I<sub>DD4R2</sub> and I<sub>DD4W2</sub> have implemented a more stringent pattern than required by JEDEC and therefore these I<sub>DD</sub> values are slightly higher than if the JEDEC pattern was used.  
7. Notes 1, 2, and 5 apply to entire table.

**Table 13: I<sub>DD</sub> Parameters at 3200 Mb/s – With Enhanced DVFSC Enabled – Single Die**

| Symbol                    | Supply            | x8 Mode |        |        | x16 Mode |        |        | Unit | Note    |
|---------------------------|-------------------|---------|--------|--------|----------|--------|--------|------|---------|
|                           |                   | UT      | AT     | IT     | UT       | AT     | IT     |      |         |
| I <sub>DD4R-DVFSC1</sub>  | V <sub>DD1</sub>  | 14.00   | 13.00  | 13.00  | 15.00    | 14.00  | 14.00  | mA   | 3, 4, 6 |
| I <sub>DD4R-DVFSC2H</sub> | V <sub>DD2H</sub> | 41.00   | 31.00  | 31.00  | 42.00    | 32.00  | 32.00  |      |         |
| I <sub>DD4R-DVFSC2L</sub> | V <sub>DD2L</sub> | 95.00   | 90.00  | 90.00  | 125.00   | 120.00 | 120.00 |      |         |
| I <sub>DD4R-DVFSCQ</sub>  | V <sub>DDQ</sub>  | 44.00   | 44.00  | 44.00  | 88.00    | 88.00  | 88.00  |      |         |
| I <sub>DD4W-DVFSC1</sub>  | V <sub>DD1</sub>  | 13.00   | 12.00  | 12.00  | 14.00    | 13.00  | 13.00  | mA   | 3, 6    |
| I <sub>DD4W-DVFSC2H</sub> | V <sub>DD2H</sub> | 39.00   | 31.00  | 31.00  | 40.00    | 32.00  | 32.00  |      |         |
| I <sub>DD4W-DVFSC2L</sub> | V <sub>DD2L</sub> | 85.00   | 80.00  | 80.00  | 115.00   | 110.00 | 110.00 |      |         |
| I <sub>DD4W-DVFSCQ</sub>  | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |
| I <sub>DD5ED1</sub>       | V <sub>DD1</sub>  | 22.00   | 20.00  | 20.00  | 22.00    | 20.00  | 20.00  | mA   |         |
| I <sub>DD5ED2H</sub>      | V <sub>DD2H</sub> | 195.00  | 180.00 | 180.00 | 195.00   | 180.00 | 180.00 |      |         |
| I <sub>DD5ED2L</sub>      | V <sub>DD2L</sub> | 25.00   | 23.00  | 23.00  | 25.00    | 23.00  | 23.00  |      |         |
| I <sub>DD5EDQ</sub>       | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |
| I <sub>DD5ABED1</sub>     | V <sub>DD1</sub>  | 3.60    | 3.30   | 3.30   | 3.60     | 3.30   | 3.30   | mA   |         |
| I <sub>DD5ABED2H</sub>    | V <sub>DD2H</sub> | 39.00   | 27.00  | 27.00  | 37.00    | 27.00  | 27.00  |      |         |
| I <sub>DD5ABED2L</sub>    | V <sub>DD2L</sub> | 23.50   | 21.50  | 21.50  | 24.00    | 22.00  | 22.00  |      |         |
| I <sub>DD5ABEDQ</sub>     | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |
| I <sub>DD5PBED1</sub>     | V <sub>DD1</sub>  | 3.60    | 3.30   | 3.30   | 3.60     | 3.30   | 3.30   | mA   |         |
| I <sub>DD5PBED2H</sub>    | V <sub>DD2H</sub> | 39.00   | 27.00  | 27.00  | 37.00    | 27.00  | 27.00  |      |         |
| I <sub>DD5PBED2L</sub>    | V <sub>DD2L</sub> | 23.50   | 21.50  | 21.50  | 24.00    | 22.00  | 22.00  |      |         |
| I <sub>DD5PBEDQ</sub>     | V <sub>DDQ</sub>  | 0.60    | 0.60   | 0.60   | 0.60     | 0.60   | 0.60   |      |         |

- Notes: 1. Published I<sub>DD</sub> values except I<sub>DD4RQ</sub> are the maximum I<sub>DD</sub> values considering the worst-case conditions of process, temperature, and voltage.
2. Enhanced DVFSC enabled, DVFSCQ enabled, 3200 Mb/s, 16B mode
3. BL = 16, DBI disabled.
4. I<sub>DD4RQ</sub> value is reference only. Typical value. Output load = 5pF; R<sub>ON</sub> = 40 ohms; T<sub>C</sub> = 25°C
5. V<sub>DD1</sub> = 1.70–1.95V; V<sub>DD2H</sub> = 1.01–1.12V; V<sub>DD2L</sub> = 0.87–0.97V; V<sub>DDQ</sub> = 0.47–0.57V (DVFSCQ disabled)/0.27–0.37V (DVFSCQ enabled)
6. I<sub>DD4R2</sub> and I<sub>DD4W2</sub> have implemented a more stringent pattern than required by JEDEC and therefore these I<sub>DD</sub> values are slightly higher than if the JEDEC pattern was used.
7. Notes 1, 2, and 5 apply to entire table.

**Table 14: Full-Array Power-Down Self Refresh Current – Single Die**

| Temperature | Symbol               | Supply            | Value | Unit | Notes |
|-------------|----------------------|-------------------|-------|------|-------|
| 25°C        | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 0.20  | mA   | 4     |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 0.5   |      |       |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | 0     |      |       |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | 0.03  |      |       |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 0.19  | mA   | 4     |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 0.49  |      |       |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | 0     |      |       |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | 0.01  |      |       |
| 45°C        | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 0.27  | mA   | 4     |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 0.92  |      |       |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | 0     |      |       |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | 0.03  |      |       |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 0.25  | mA   | 4     |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 0.92  |      |       |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | 0     |      |       |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | 0.01  |      |       |
| 65°C        | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 0.48  | mA   | 4     |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 2.30  |      |       |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | 0     |      |       |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | 0.03  |      |       |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 0.46  | mA   | 4     |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 2.30  |      |       |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | 0     |      |       |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | 0.01  |      |       |
| 85°C        | I <sub>DD61</sub>    | V <sub>DD1</sub>  | 4.00  | mA   | 4     |
|             | I <sub>DD62H</sub>   | V <sub>DD2H</sub> | 23.00 |      |       |
|             | I <sub>DD62L</sub>   | V <sub>DD2L</sub> | 0.20  |      |       |
|             | I <sub>DD6Q</sub>    | V <sub>DDQ</sub>  | 0.60  |      |       |
|             | I <sub>DD6DS1</sub>  | V <sub>DD1</sub>  | 4.00  | mA   | 4     |
|             | I <sub>DD6DS2H</sub> | V <sub>DD2H</sub> | 23.00 |      |       |
|             | I <sub>DD6DS2L</sub> | V <sub>DD2L</sub> | 0.20  |      |       |
|             | I <sub>DD6DSQ</sub>  | V <sub>DDQ</sub>  | 0.60  |      |       |

Notes: 1. I<sub>DD6</sub> 25/45/65°C is the typical value in the distribution with nominal V<sub>DD</sub> and a reference-only value. I<sub>DD6</sub> 85°C is the maximum I<sub>DD</sub> guaranteed value considering the worst-case conditions of process, temperature, and voltage.

2. DVFS and DVFSQ disabled.

3. V<sub>DD1</sub> = 1.70–1.95V; V<sub>DD2H</sub> = 1.01–1.12V; V<sub>DD2L</sub> = 0.87–0.97V; V<sub>DDQ</sub> = 0.47–0.57V

4. While entering and exiting Self-Refresh modes, all defined/used supply rails (V<sub>DD1</sub>, V<sub>DD2H</sub>, V<sub>DD2L</sub>, V<sub>DDQ</sub>) are required to be at valid levels. After the Self-Refresh with Power down mode entrance commands are completed and t<sub>ESPD</sub> timing requirement has been satisfied, the V<sub>DDQ</sub> power rail may be turned off by the controller.

## Revision History

### Rev. G – 06/2026

- Updated Part Number Ordering Information

### Rev. F – 03/2026

- Updated legal status to Production

### Rev. E – 03/2026

- Updated Features Page
- Updated Functional Safety Page
- Updated Automotive Product Notes Page

### Rev. D – 01/2026

- Updated CS Rx and DQ Rx Mask for 9600 Mbps
- Updated Package Thermal Impedance Characteristics table for 8DP
- Specified  $I_{DD}$  values for UT
- Added  $I_{DD}$  6 values for 45/65C

### Rev. C – 12/2025

- Removed 8533 and 7500 Mb/s part numbers and their related information
- Updated Package Thermal Impedance Characteristics table
- Specified  $I_{DD}$  values for IT and AT

### Rev. B – 09/2025

- Updated legal status to Preliminary
- Added Functional Safety, DLEP & RAS Notes
- Updated Package Thermal Impedance Characteristics table

### Rev. A – 06/2024

- Initial Advanced data sheet release

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This data sheet contains minimum and maximum limits specified over the power supply and temperature range set forth herein.  
 Although considered final, these specifications are subject to change, as further product development and data characterization sometimes occur.